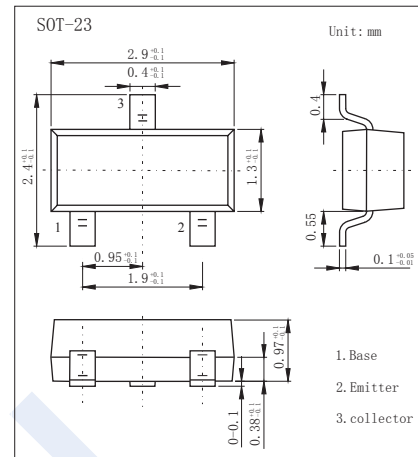


## PNP Transistors

### 2SA1035-HF

#### Features

- Low noise voltage NV.
- High forward current transfer ratio  $h_{FE}$ .
- Complementary to 2SC2406-HF.
- Pb-Free Package May be Available. The G-Suffix Denotes a Pb-Free Lead Finish



#### Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

| Parameter                   | Symbol    | Rating      | Unit             |
|-----------------------------|-----------|-------------|------------------|
| Collector-base voltage      | $V_{CBO}$ | -55         | V                |
| Collector-emitter voltage   | $V_{CEO}$ | -55         | V                |
| Emitter-base voltage        | $V_{EBO}$ | -5          | V                |
| Collector current           | $I_C$     | -50         | mA               |
| Peak collector current      | $I_{CP}$  | -100        | mA               |
| Collector power dissipation | $P_C$     | 200         | mW               |
| Junction temperature        | $T_j$     | 150         | $^\circ\text{C}$ |
| Storage temperature         | $T_{stg}$ | -55 to +150 | $^\circ\text{C}$ |

#### Electrical Characteristics $T_a = 25^\circ\text{C}$

| Parameter                            | Symbol        | Test Conditions   | Min | Typ | Max  | Unit          |
|--------------------------------------|---------------|---|-----|-----|------|---------------|
| Collector- base breakdown voltage    | $V_{CBO}$     | $I_C = -100 \mu\text{A}$ , $I_E = 0$  | -55 |     |      | V             |
| Collector- emitter breakdown voltage | $V_{CEO}$     | $I_C = -2 \text{ mA}$ , $I_B = 0$   | -55 |     |      |               |
| Emitter - base breakdown voltage     | $V_{EBO}$     | $I_E = -100 \mu\text{A}$ , $I_C = 0$  | -5  |     |      |               |
| Collector-base cut-off current       | $I_{CBO}$     | $V_{CB} = -50 \text{ V}$ , $I_E = 0$  |     |     | -100 | nA            |
| Collector- emitter cut-off current   | $I_{CEO}$     | $V_{CE} = -40 \text{ V}$ , $I_B = 0$  |     |     | -1   | $\mu\text{A}$ |
| Emitter cut-off current              | $I_{EBO}$     | $V_{EB} = -5 \text{ V}$ , $I_C = 0$   |     |     | -100 | nA            |
| Collector-emitter saturation voltage | $V_{CE(sat)}$ | $I_C = -100 \text{ mA}$ , $I_B = -10 \text{ mA}$  |     |     | -0.6 | V             |
| Base - emitter saturation voltage    | $V_{BE(sat)}$ | $I_C = -100 \text{ mA}$ , $I_B = -10 \text{ mA}$  |     |     | -1.2 |               |
| Base - emitter voltage               | $V_{BE}$      | $V_{BE} = -1 \text{ V}$ , $I_C = -100 \text{ mA}$   |     |     | -1.0 |               |
| DC current gain                      | $h_{FE}$      | $V_{CE} = -5 \text{ V}$ , $I_C = -2 \text{ mA}$   | 180 |     | 700  |               |
| Noise voltage                        | NV            | $V_{CE} = -10 \text{ V}$ , $I_C = -1 \text{ mA}$ , $G_v = 80 \text{ dB}$<br>$R_g = 100 \text{ k}\Omega$ , Function = FLAT |     |     | 150  | mV            |
| Transition frequency                 | $f_T$         | $V_{CB} = -5 \text{ V}$ , $I_E = -2 \text{ mA}$ , $f = 200 \text{ MHz}$   |     | 200 |      | MHz           |

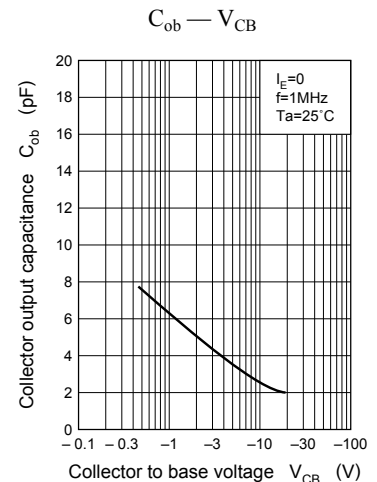
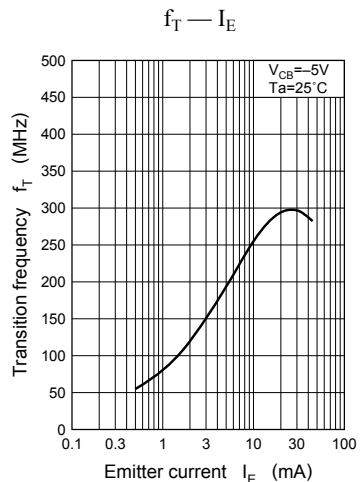
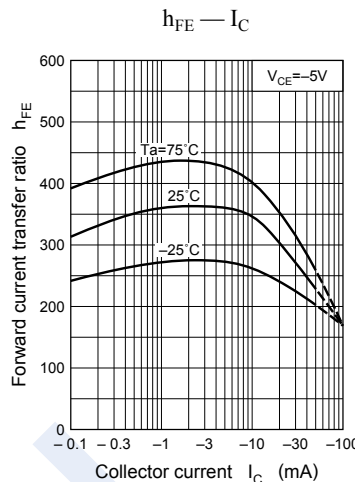
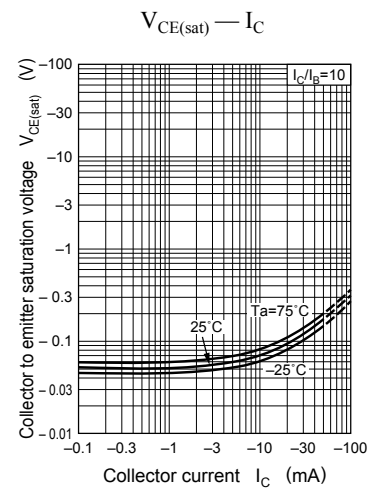
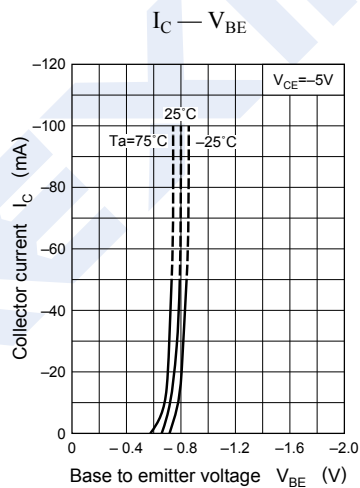
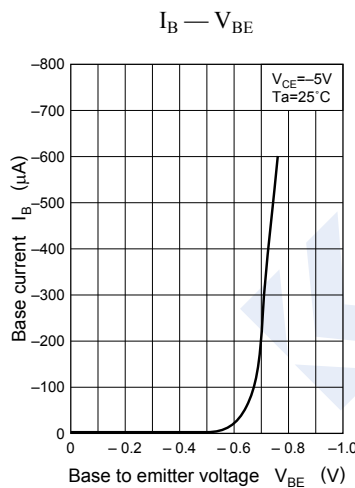
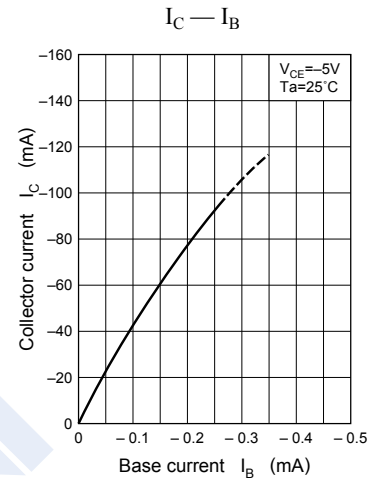
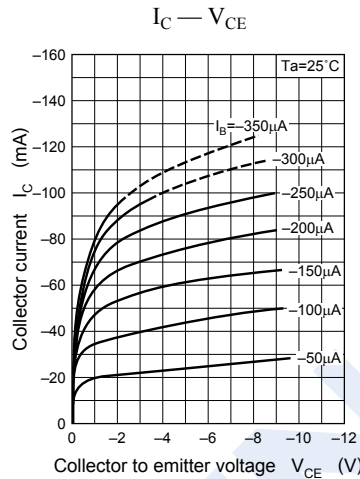
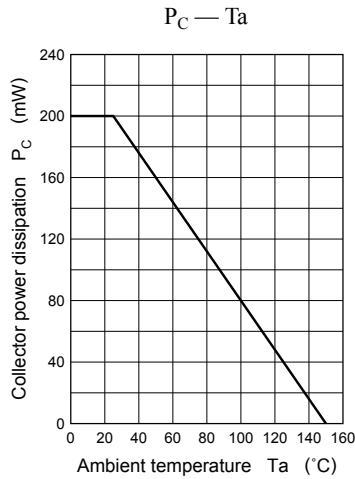
#### Classification of $h_{FE}$

| Type    | 2SA1035-R-HF    | 2SA1035-S-HF    | 2SA1035-T-HF    |
|---------|-----------------|-----------------|-----------------|
| Range   | 180-360         | 260-520         | 360-700         |
| Marking | HR <sub>F</sub> | HS <sub>F</sub> | HT <sub>F</sub> |

# PNP Transistors

## 2SA1035-HF

### Typical Characteristics



## PNP Transistors 2SA1035-HF

■ Typical Characteristics

